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# **DESCRIPTION:**

The CENTRAL SEMICONDUCTOR 2N2857 and 2N3839 are silicon NPN RF transistors designed for VHF/UHF amplifier, oscillator and converter applications.

## MARKING: FULL PART NUMBER

MAXIMUM RATINGS: (TA=25°C unless otherwise noted)

| ······································     | SYMBOL                            |             | UNITS |
|--------------------------------------------|-----------------------------------|-------------|-------|
| Collector-Base Voltage                     | V <sub>CBO</sub>                  | 30          | V     |
| Collector-Emitter Voltage                  | VCEO                              | 15          | V     |
| Emitter-Base Voltage                       | V <sub>EBO</sub>                  | 2.5         | V     |
| Continuous Collector Current               | IС                                | 40          | mA    |
| Power Dissipation                          | PD                                | 200         | mW    |
| Power Dissipation (T <sub>C</sub> =25°C)   | PD                                | 300         | mW    |
| Operating and Storage Junction Temperature | т <sub>Ј</sub> , т <sub>stg</sub> | -65 to +200 | °C    |

# ELECTRICAL CHARACTERISTICS: (T<sub>A</sub>=25°C unless otherwise noted)

|                                |                                                                              |      | <u>2N2857</u> |      | <u>2N3839</u> |       |
|--------------------------------|------------------------------------------------------------------------------|------|---------------|------|---------------|-------|
| SYMBOL                         | TEST CONDITIONS                                                              | MIN  | MAX           | MIN  | MAX           | UNITS |
| ICBO                           | V <sub>CB</sub> =15V                                                         | -    | 10            | -    | 10            | nA    |
| ICBO                           | V <sub>CB</sub> =15V, T <sub>A</sub> =150°C                                  | -    | 1.0           | -    | 1.0           | μA    |
| BVCBO                          | Ι <sub>C</sub> =1.0μΑ                                                        | 30   | -             | 30   | -             | V     |
| BVCEO                          | I <sub>C</sub> =3.0mA                                                        | 15   | -             | 15   | -             | V     |
| BVEBO                          | Ι <sub>Ε</sub> =10μΑ                                                         | 2.5  | -             | 2.5  | -             | V     |
| h <sub>FE</sub>                | V <sub>CE</sub> =1.0V, I <sub>C</sub> =3.0mA                                 | 30   | 150           | 30   | 150           |       |
| fT                             | V <sub>CE</sub> =6.0V, I <sub>C</sub> =5.0mA, f=100MHz                       | 1.0  | 1.9           | 1.0  | 2.0           | GHz   |
| Cob                            | $V_{CB}$ =10V, I <sub>E</sub> =0, f=100kHz to 1.0MHz                         | -    | 1.0           | -    | 1.0           | pF    |
| Po                             | V <sub>CB</sub> =10V, I <sub>C</sub> =12mA, f=500MHz                         | 30   | -             | 30   | -             | mW    |
| G <sub>pe</sub>                | $V_{CE}$ =6.0V, I <sub>C</sub> =1.5mA, f=450MHz, R <sub>S</sub> =50 $\Omega$ | 12.5 | 19            | 12.5 | 19            | dB    |
| NF                             | $V_{CE}$ =6.0V, I <sub>C</sub> =1.5mA, f=450MHz, R <sub>S</sub> =50 $\Omega$ | -    | 4.5           | -    | 3.9           | dB    |
| r <sub>b</sub> 'C <sub>C</sub> | V <sub>CB</sub> =6.0V, I <sub>C</sub> =2.0mA, f=31.9MHz                      | 4.0  | 15            | 1.0  | 15            | ps    |

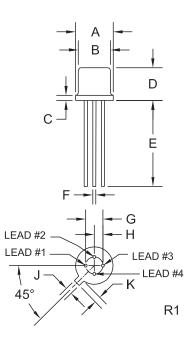


R1 (31-January 2013)



2N2857 2N3839

NPN SILICON RF TRANSISTORS



| DIMENSIONS |        |       |             |      |  |  |
|------------|--------|-------|-------------|------|--|--|
|            | INCHES |       | MILLIMETERS |      |  |  |
| SYMBOL     | MIN    | MAX   | MIN         | MAX  |  |  |
| A (DIA)    | 0.209  | 0.230 | 5.31        | 5.84 |  |  |
| B (DIA)    | 0.175  | 0.195 | 4.45        | 4.95 |  |  |
| С          | -      | 0.030 | -           | 0.76 |  |  |
| D          | 0.170  | 0.210 | 4.32        | 5.33 |  |  |
| Е          | 0.500  | -     | 12.70       | -    |  |  |
| F (DIA)    | 0.016  | 0.019 | 0.41        | 0.48 |  |  |
| G (DIA)    | 0.100  |       | 2.54        |      |  |  |
| Н          | 0.050  |       | 1.27        |      |  |  |
| J          | 0.036  | 0.046 | 0.91        | 1.17 |  |  |
| К          | 0.028  | 0.048 | 0.71        | 1.22 |  |  |

10-72 (REV: R1)

LEAD CODE:

1) Emitter

2) Base

3) Collector

4) Case

MARKING: FULL PART NUMBER

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#### **TO-72 CASE - MECHANICAL OUTLINE**

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# OUTSTANDING SUPPORT AND SUPERIOR SERVICES

#### PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options

#### DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free guick ship samples (2<sup>nd</sup> day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- · Environmental regulation compliance
- Customer specific screening
- · Up-screening capabilities

· Custom product packing

Custom bar coding for shipments

- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- · Application and design sample kits
- · Custom product and package development

## REQUESTING PRODUCT PLATING

- If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when 1. ordering (example: 2N2222A TIN/LEAD).
- 2. If requesting Lead (Pb) Free plated devices, add the suffix " PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

## CONTACT US

## **Corporate Headquarters & Customer Support Team**

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